Quad 2-Input AND Gate

The MC10104 is a quad 2-input AND gate. One of the gates has both AND/NAND outputs available.

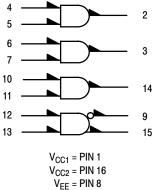
- $P_D = 35 \text{ mW typ/gate (No Load)}$
- $t_{pd} = 2.7 \text{ ns typ}$
- t_r , $t_f = 2.0$ ns typ (20%–80%)

ON

ON Semiconductor

http://onsemi.com

LOGIC DIAGRAM



DIP

PIN ASSIGNMENT



Pin assignment is for Dual–in–Line Package.
For PLCC pin assignment, see the Pin Conversion Tables on page 18 of the ON Semiconductor MECL Data Book (DL122/D).



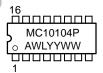
CDIP-16 L SUFFIX CASE 620



MARKING DIAGRAMS



PDIP-16 P SUFFIX CASE 648





PLCC-20 FN SUFFIX CASE 775



A = Assembly Location

WL = Wafer Lot YY = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC10104L	CDIP-16	25 Units / Rail
MC10104P	PDIP-16	25 Units / Rail
MC10104FN	PLCC-20	46 Units / Rail

ELECTRICAL CHARACTERISTICS

				Test Limits							
Characteristic			Pin Under Test	−30°C		+25°C			+85°C		1
		Symbol		Min	Max	Min	Тур	Max	Min	Max	Unit
Power Supply	Drain Current	Ι _Ε	8		39			35		39	mAdc
Input Current		I _{inH} *	12 13		425 350			265 220		265 220	μAdc
		I _{inL}	12	0.5		0.5			0.3		μAdc
Output Voltage	e Logic 1	V _{OH}	15 9	-1.060 -1.060	-0.890 -0.890	-0.960 -0.960		-0.810 -0.810	-0.890 -0.890	-0.700 -0.700	Vdc
Output Voltage	e Logic 0	V _{OL}	15 9	-1.890 -1.890	-1.675 -1.675	-1.850 -1.850		-1.650 -1.650	-1.825 -1.825	-1.615 -1.615	Vdc
Threshold Vol	ltage Logic 1	V _{OHA}	9 9 15 15	-1.090 -1.090 -1.090 -1.090		-0.980 -0.980 -0.980 -0.980			-0.910 -0.910 -0.910 -0.910	CIC	Vdc
Threshold Vol	tage Logic 0	V _{OLA}	9 9 15 15		-1.655 -1.655 -1.655 -1.655			-1.630 -1.630 -1.630 -1.630		-1.595 -1.595 -1.595 -1.595	Vdc
Switching Tim	nes (50Ω Load)										ns
Propagation D	Delay	t ₁₂₊₁₅₊ t ₁₂₋₁₅₋ t ₁₂₊₉₋ t ₁₂₋₉₊	15 15 9 9	1.0 1.0 1.0 1.0	4.3 4.3 4.3 4.3	1.0 1.0 1.0 1.0	2.2 2.2 2.2 2.2	4.0 4.0 4.0 4.0	1.0 1.0 1.0 1.0	4.2 4.2 4.2 4.2	
		t ₁₃₊₁₅₊ t ₁₃₊₉₋	15 9	1.0 1.0	4.3 4.3	1.0 1.0	2.7 2.7	4.0 4.0	1.0 1.0	4.2 4.2	
Rise Time	(20 to 80%)	t ₁₅₊ t ₉₊	15 9	1.5 1.5	3.7 3.7	1.5 1.5	2.0 2.0	3.5 3.5	1.5 1.5	3.6 3.6	
Fall Time	(20 to 80%)	t _{15–} t _{9–}	15 9	1.5 1.5	3.7 3.7	1.5 1.5	2.0 2.0	3.5 3.5	1.5 1.5	3.6 3.6	

^{*} Inputs 4, 7, 10 and 13 will behave similarly for ac and l_{inH} values. Inputs 5, 6, 11 and 12 will behave similarly for ac and l_{inH} values.

ELECTRICAL CHARACTERISTICS (continued)

					TEST VOI	TAGE VALU	JES (Volts)		
		@ Test Te	mperature	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	
			-30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
			Pin	TEST VOLTAGE APPLIED TO PINS LISTED BELOW					
Characteristic		Symbol	Under Test	V _{IHmax}	V _{ILmin}	V _{IHAmin}	V _{ILAmax}	V _{EE}	(V _{CC}) Gnd
Power Supply Drain C	Current	ΙE	8					8	1, 16
Input Current		I _{inH*}	12 13	12, 13 13				8 8	1, 16 1, 16
		I _{inL}	12		12			8	1, 16
Output Voltage	Logic 1	V _{OH}	15 9	12, 13				8 8	1, 16 1, 16
Output Voltage	Logic 0	V _{OL}	15 9	12, 13				8 8	1, 16 1, 16
Threshold Voltage	Logic 1	V _{OHA}	9 9 15 15	12 13		13 12	12 13	8 8 8	1, 16 1, 16 1, 16 1, 16
Threshold Voltage	Logic 0	V _{OLA}	9 9 15 15	12 13	7/	13 12	12 13	8 8 8	1, 16 1, 16 1, 16 1, 16
Switching Times	(50Ω Load)			+1.11V		Pulse In	Pulse Out	-3.2 V	+2.0 V
Propagation Delay		t ₁₂₊₁₅₊ t ₁₂₋₁₅₋ t ₁₂₊₉₋ t ₁₂₋₉₊	15 15 9 9	13 13 13 13	(O)	12 12 12 12	15 15 9 9	8 8 8	1, 16 1, 16 1, 16 1, 16
		t ₁₃₊₁₅₊ t ₁₃₊₉₋	15 9	12 12		13 13	15 9	8 8	1, 16 1, 16
Rise Time	(20 to 80%)	t ₁₅₊ t ₉₊	15 9	12 12		13 13	15 9	8 8	1, 16 1, 16
Fall Time	(20 to 80%)	t ₁₅₋	15 9	12 12		13 13	15 9	8 8	1, 16 1, 16

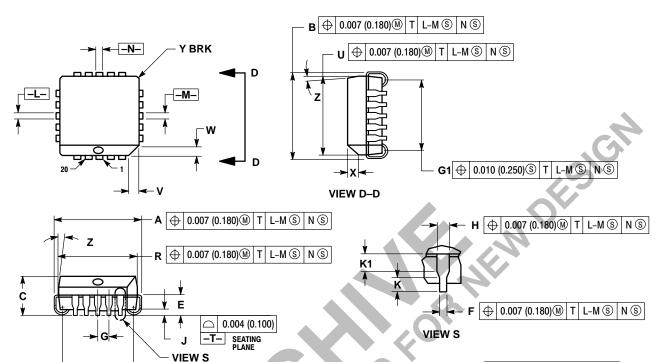
^{*} Inputs 4, 7, 10 and 13 will behave similarly for ac and I_{inH} values. Inputs 5, 6, 11 and 12 will behave similarly for ac and I_{inH} values.

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50-ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

PACKAGE DIMENSIONS

PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE C



NOTES:

G1 ⊕ 0.010 (0.250)③ T L-M ⑤ N ⑤

OF VICE NOT PRESCO

- IOTES:

 1. DATUMS -L-, -M-, AND -N- DETERMINED WHERE TOP OF LEAD SHOULDER EXITS PLASTIC BODY AT MOLD PARTING LINE.

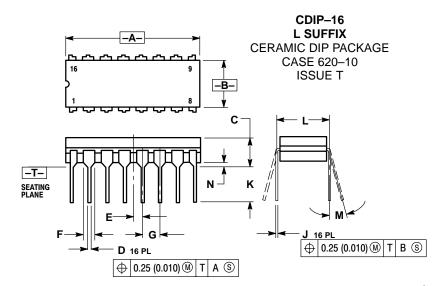
 2. DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.

 4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.
- DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INCHES		MILLIM	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.385	0.395	9.78	10.03
В	0.385	0.395	9.78	10.03
С	0.165	0.180	4.20	4.57
Ε	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.350	0.356	8.89	9.04
U	0.350	0.356	8.89	9.04
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2°	10°	2°	10 °
G1	0.310	0.330	7.88	8.38
K1	0.040		1.02	

PACKAGE DIMENSIONS



NOTES:

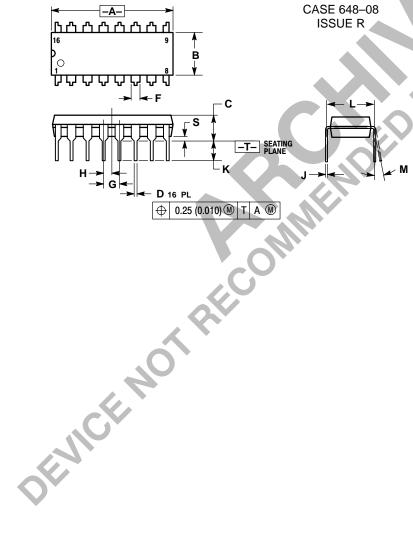
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION LTO CENTER OF LEAD WHEN CONTROLLING DIMENSION LTO CENTER OF LEAD WHEN

- FORMED PARALLEL

 DIMENSION F MAY NARROW TO 0.76 (0.030)
 WHERE THE LEAD ENTERS THE CERAMIC
 BODY.

	INC	HES	MILLIMETERS		
DIM	MIN MAX		MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.015 0.020		0.50	
E	0.050	BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100	BSC	2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300	BSC	7.62	BSC	
M	0 °	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL

	INC	HES	MILLIN	IETERS	
DIM	MIN MAX		MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
C	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
M	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

Notes



Notes





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